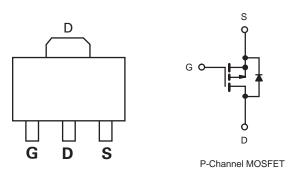


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P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	R _{DS(on)} (Ω)	$R_{DS(on)}$ (Ω) I_{D} (A) G			
- 30	0.039 at V _{GS} = - 10 V	7.6 ^a	15 nC		
	0.053 at V _{GS} = - 4.5 V	6 ^a	13110		



FEATURES

- DT-Trench Power MOSFET
- 100 % R_g Tested

APPLICATIONS

- DC/DC Converter
 - Load Switch
 - Adaptor Switch



Parameter		Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	- 30	V		
Gate-Source Voltage		V _{GS}	± 20	v	
	T _C = 25 °C		- 7.6 ^a	_	
Continuous Drain Current (T ₁ = 150 °C)	T _C = 85 °C	I _D	- 5.8		
	T _A = 25 °C	טי	- 6 ^{a, b, c}		
	T _A = 85 °C		- 5.2 ^{b, c}	A	
Pulsed Drain Current		I _{DM}	- 22.8		
Continuous Source-Drain Diode Current	T _C = 25 °C	I _S	- 5.3	7	
	T _A = 25 °C	'S	- 2.1 ^{b, c}		
Maximum Power Dissipation	T _C = 25 °C		6.3		
	T _C = 85 °C	P _D	3.3	W	
	T _A = 25 °C	' D	2.5 ^{b, c}		
	T _A = 85 °C		1.3 ^{b, c}		
Operating Junction and Storage Temperature R	T _J , T _{stg}	- 55 to 150	°C		
Soldering Recommendations (Peak Temperatur	, i i i i i i i i i i i i i i i i i i i	260			

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient	t ≤ 5 s	R _{thJA}	40	50	°C/W	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	15	20		

Notes:

a. Package limited.b. Surface Mounted on 1" x 1" FR4 board.

c. t = 5 s.

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SPECIFICATIONS $T_J = 25 \text{ °C}$, Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static	Cymbol			Typ.	max.		
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0 V, I _D = - 250 μA	- 30			V	
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_J$			- 30		- mV/°C	
V _{GS(th)} Temperature Coefficient	ΔV _{GS(th)} /T _J	I _D = - 250 μA		5			
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = - 250 μA	- 0.8	-	- 1.5	V	
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$	- 0.0		± 100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			- 1	μΑ	
		$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 85 \text{ °C}$			- 5		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le -5 V, V_{GS} = -10 V$	- 20			A	
		V _{GS} = - 10 V, I _D = - 7.2 A		0.039	0.043	+	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -6.0 \text{ A}$		0.053	0.059	Ω	
Forward Transconductance ^a	g _{fs}	V _{DS} = - 15 V, I _D = - 7.2 A		18		S	
Dynamic ^b	0.0						
Input Capacitance	C _{iss}			1340			
Output Capacitance	C _{oss}	V _{DS} = - 15 V, V _{GS} = 0 V, f = 1 MHz		215		pF	
Reverse Transfer Capacitance	C _{rss}			185			
		V _{DS} = - 15 V, V _{GS} = - 10 V, I _D = - 7.2 A		28	42	nC	
Total Gate Charge	Qg			15	23		
Gate-Source Charge	Q _{gs}	V_{DS} = - 15 V, V_{GS} = - 4.5 V, I_{D} = - 7.2 A		4.5			
Gate-Drain Charge	Q _{gd}			7.2			
Gate Resistance	Rg	f = 1 MHz	1.2	6	12	Ω	
Turn-On Delay Time	t _{d(on)}			50			
Rise Time	t _r	V_{DD} = - 15 V, R_L = 2.6 Ω		140		- - - -	
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong$ - 5.8 A, V_GEN = - 4.5 V, R_g = 1 Ω		30			
Fall Time	t _f			18			
Turn-On Delay Time	t _{d(on)}			11			
Rise Time	t _r	V_{DD} = - 15 V, R _L = 2.6 Ω		11			
Turn-Off Delay Time	t _{d(off)}	$I_D \cong$ - 5.8 A, V_{GEN} = - 10 V, R_g = 1 Ω		37			
Fall Time	t _f			12			
Drain-Source Body Diode Characteristi	cs	· · · · · ·					
Continuous Source-Drain Diode Current	۱ _S	T _C = 25 °C			- 5.3	A	
Pulse Diode Forward Current	I _{SM}				- 22.8		
Body Diode Voltage	V _{SD}	$I_{S} = -5.8 \text{ A}, V_{GS} = 0 \text{ V}$		- 0.8	- 1.2	V	
Body Diode Reverse Recovery Time	t _{rr}			22	33	ns	
Body Diode Reverse Recovery Charge	Q _{rr}	I _F = - 5.8 A, dl/dt = - 100 A/μs, T _J = 25 °C		15	25	nC	
Reverse Recovery Fall Time	t _a	_F = 0.07, αναι = 1007γμ3, 1j = 20 0		13		00	
Reverse Recovery Rise Time t _b		[9		ns	

Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

 $V_{GS} = -10$ thru -4 V

T_C = - 55 °C

5

4

3

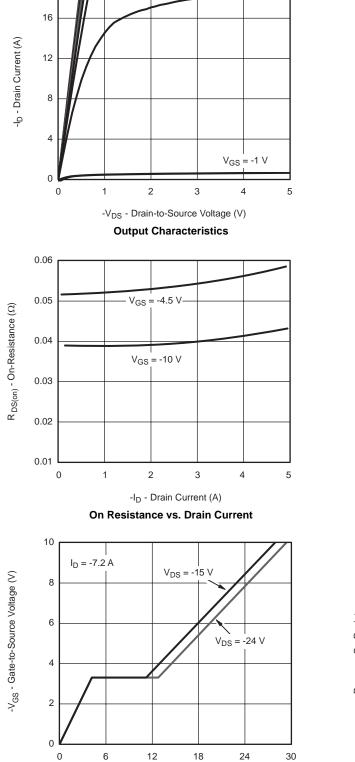
2

1

0

0.0

-I_D - Drain Current (A)



Q_g - Total Gate Charge (nC)

Gate Charge



1.5

2.0

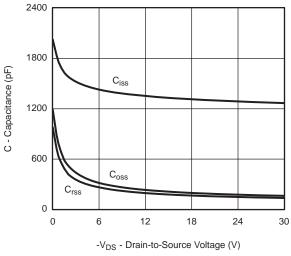
2.5

1.0

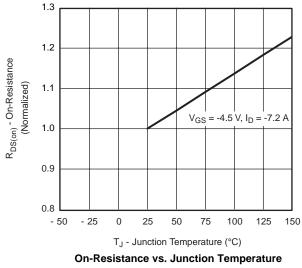
T_C = 25 °C

T_C = 125 °C

0.5

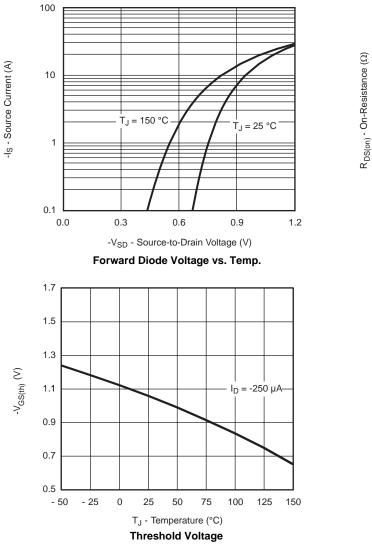


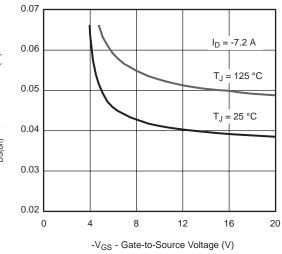
Capacitance



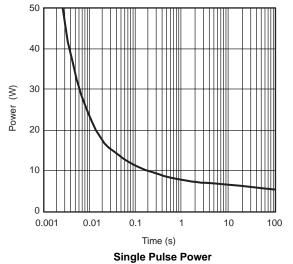
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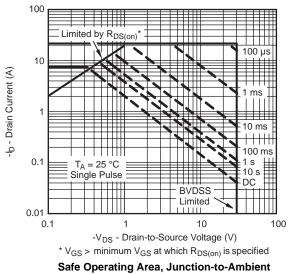
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





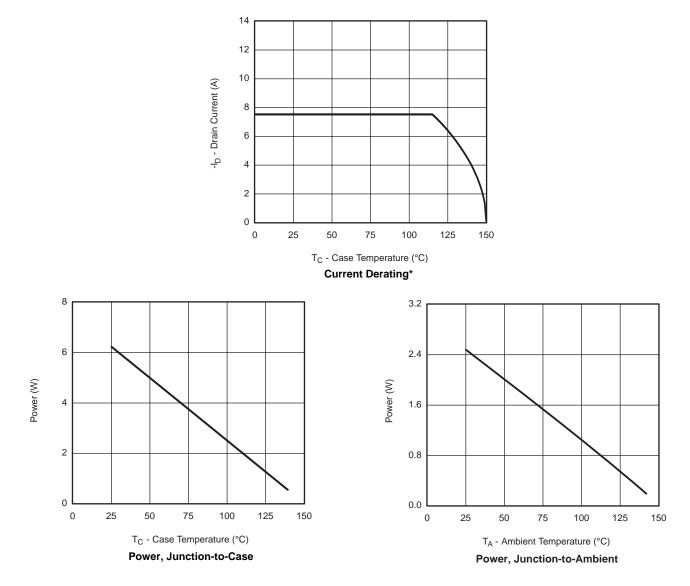
On-Resistance vs. Gate-to-Source Voltage







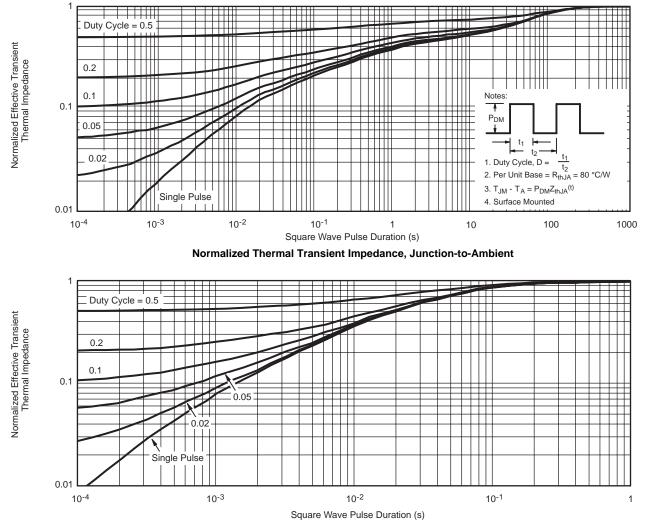
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



* The power dissipation P_D is based on $T_{J(max)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot



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